

Lead-free Green DMN32D2LV

DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.2V max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 3)

Mechanical Data

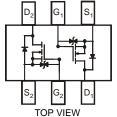
- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)





SOT-563

TOP VIEW



Schematic and Transistor Diagram

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±10	V
Drain Current (Note 1)	ID	400	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Total Power Dissipation (Note 1)	PD	400	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ ext{ heta}JA}$	313	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 4)								
Drain-Source Breakdown Voltage		BV _{DSS}	30	_		V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	@ T _C = 25°C	I _{DSS}			1	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Body Leakage		I _{GSS}			±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
Cate Dody Leakage		IGSS	_		±500	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 4)	ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage		V _{GS(th)}	0.6		1.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			_		2.2		$V_{GS} = 1.8V, I_D = 20mA$	
Static Drain-Source On-Resistance		R _{DS (ON)}			1.5	Ω	$V_{GS} = 2.5V, I_D = 20mA$	
			_	_	1.2		$V_{GS} = 4.0V, I_D = 100mA$	
Forward Transconductance	Y _{fs}	100		_	mS	$V_{DS} = 10V, I_{D} = 0.1A$		
Source-Drain Diode Forward Voltage			0.5	_	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$	
DYNAMIC CHARACTERISTICS								
Input Capacitance			_	39	—	pF		
Output Capacitance			_	10	_	pF	V _{DS} = 3V, V _{GS} = 0V f = 1.0MHz	
Reverse Transfer Capacitance			_	3.6	_	pF		
Switching Time	Turn-on Time	t _{on}		11		nS	$V_{DD} = 5V, I_D = 10 \text{ mA},$	
Switching Time	Turn-off Time	t _{off}		51		nS	$V_{GS} = 5V$	

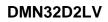
Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.

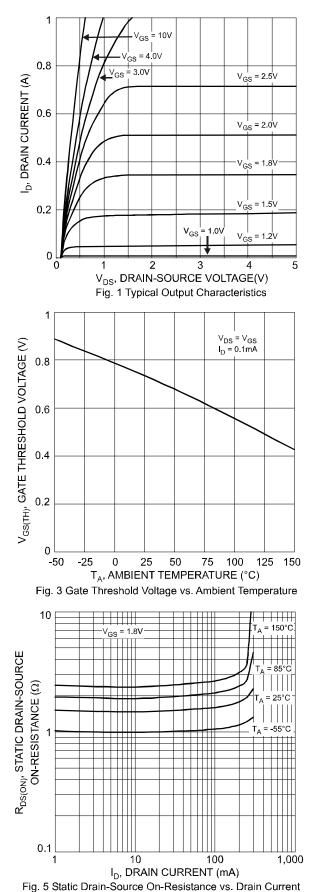
2. No purposefully added lead.

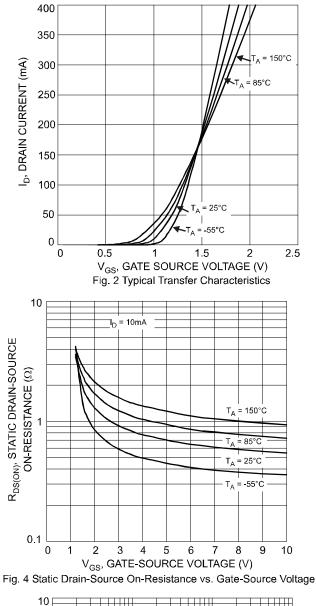
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

4. Short duration pulse test used to minimize self-heating effect.









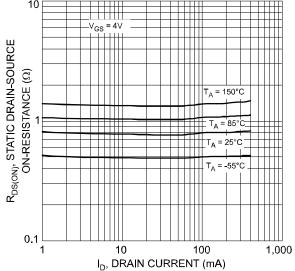
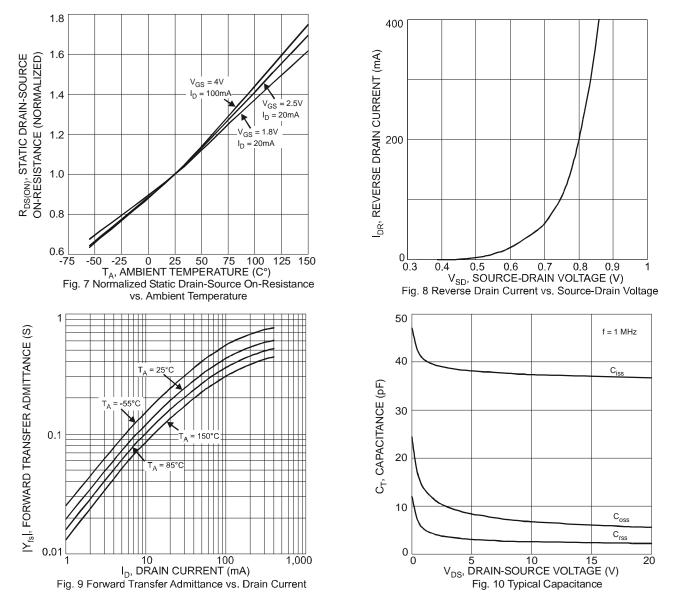


Fig. 6 Static Drain-Source On-Resistance vs. Drain Current



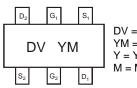


Ordering Information (Note 5)

Part Number	Case	Packaging
DMN32D2LV-7	SOT-563	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information (Note 6)



 $\begin{array}{l} \mathsf{DV} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \ (\mathsf{See} \ \mathsf{Note} \ 6) \\ \mathsf{YM} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex:} \ \mathsf{U} = 2007) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex:} \ 9 = \mathsf{September}) \end{array}$

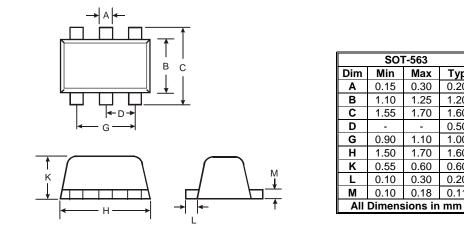
Notes: 6. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

Date Code Key

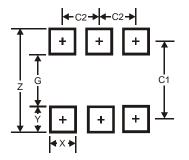
Year	20	07	20	08	20	09	20	10	20	11	20	12
Code	ι	J	١	/	٧	V)	<	١	(Z	2
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5

Typ 0.20

1.20

1.60

0.50

1.00

1.60

0.60

0.20

0.11



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